



GOVERNMENT POLYTECHNIC DARLIPALI, SUNDARGARH

ସରକାରୀ ବହୁବୃତ୍ତି ଅନୁଷ୍ଠାନ ଦଲିପାଲି, ସୁନ୍ଦରଗଡ଼

GOVERNMENT OF ODISHA | ଓଡ଼ିଶା ସରକାର

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Department of Applied Electronics and Instrumentation Engg.

LESSON PLAN(2025-26)

Discipline: AE&I ENGG.	Semester: 3RD	Name of the Teaching Faculty: PARTHA SARATHI MALLICK
Subject: ELECTRONICS DEVICES (AEIEPC209)	No. of days/ per week class allotted: 3	Semester From Date : 14/07/2025 to Date: 15/11/2025 No. of Weeks: 15
Week	Class Day	Theory/ Practical Topics
1st	1st	Introduction to Semiconductor Physics: Review of Quantum Mechanics ,Electrons in periodic Lattices
	2nd	Energy bands in intrinsic and extrinsic silicon
	3rd	Carrier transport: Diffusion current, Drift current, Mobility and resistivity
2nd	1st	P-N Junction Diodes: Generation and recombination of carriers
	2nd	Poisson and continuity equation
	3rd	P-N Junction Diodes: Construction of P-N Junction Diode, Operating Principle
3rd	1st	P-N junction characteristics, I-V characteristics
	2nd	Small signal switching models
	3rd	Zener Diode.
4th	1st	Avalanche breakdown
	2nd	Schottky diode
	3rd	LED
5th	1st	Photodiode and solar cell
	2nd	Bipolar Junction Transistor (BJT): Construction of BJT, Operating Principle of BJT, Types of BJT
	3rd	Working principle of p-n-p and n-p-n BJT, I-V characteristics
6th	1st	Ebers Moll Model
	2nd	Different types of transistor connection: Common Base (CB), Common Emitter (CE), Common Collector (CC)
	3rd	Input and output characteristics of transistor in different connections
7th	1st	Define ALPHA, BETA and GAMMA of transistors in various modes, Establish the Mathematical relationship between ALPHA, BETA and GAMMA
	2nd	Basic concept of Biasing
	3rd	Types of Biasing
8th	1st	h-parameter model of BJT
	2nd	Load line and determine the Q-point.
	3rd	Types of Coupling, Working principle and use of R-C Coupled Amplifier
9th	1st	Frequency Responses of R-C coupled Amplifier
	2nd	FIELD EFFECT TRANSISTOR (FET): FET & its classifications

	3rd	Differentiate between JFET & BJT
10th	1st	Construction, working principle & characteristics of JEFT
	2nd	Parameters of JFET & establish relation among JFET parameters
	3rd	JEFT as an amplifier
11th	1st	Construction and working principle of MOSEFT, Classification of MOSEFT
	2nd	Characteristics (Drain & Transfer) of MOSEFT
	3rd	Explain the operation of CMOS, VMOS & LD MOS.
12th	1st	FEED BACK AMPLIFIER & OSCILLATOR: Define & classify Feedback Amplifier
	2nd	Types of feedback – negative & positive feedback.
	3rd	Characteristics voltage gain, bandwidth, input Impedance output impedance, stability, noise and distortion in amplifiers.
13th	1st	Oscillator: Block diagram of sine wave oscillator
	2nd	Types Requirement of oscillation
	3rd	Barkhausen criterion
14th	1st	LC oscillators: Colpitts Oscillators
	2nd	Hartley Oscillators
	3rd	Wien Bridge Oscillators
15th	1st	Integrated Circuit Fabrication Process: Oxidation, Diffusion, Ion implantation
	2nd	Photo-lithography, Etching
	3rd	Chemical vapor deposition, Sputtering, Twin-tub CMOS process

Prepared By-


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